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Applicant:

Christoph A. Wasshuber

Art Unit:

2818

Serial No.:

10/714,366

Examiner:

Nguyen, T.

Filing Date:

11/13/2003

Docket No.:

TI-36280

Customer No.: 23494

Conf. No.:

1864

Title: FORMING A SEMICONDUCTOR STRUCTURE IN MANUFACTURING A SEMICONDUCTOR DEVICE USING ONE OR MORE EPITAXIAL GROWTH

PROCESSES

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